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General Description:

Gallium aluminum arsenide infrared emitting diode optically coupled to an electrically isolated silicon photo-darlington transistor; forward voltage 1.45 maximum volts; forward current 10.0 ma dc; 0.330 in. Lg;

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A23900